Ultrafast Recovery Rectifier DURF2040CT, 2x 10A, 400V, ITO-220AB, Common Cathode



RoHS

e3

DURF2040CT



Circuit Diagram



Base Common

Description

Littelfuse DUR series Ultrafast Recovery Rectifier is designed to meet the general requirements of commercial applications by providing low Trr, high-temperature, lowleakage and low forward voltage drop products. It is suitable for output rectifier, free-wheeling or boost diode in high-frequency power switching application such as switch mode power supply and DC-DC converters.

Features

- Ultra-fast switching
- Low reverse leakage
 current

configuration in electrically isolated ITO-220AB package

• Pb-free E3 means 2nd

level interconnect is Pb-

material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

free and the terminal finish

- High surge current
 capability
- Low forward voltage drop
- Common Cathode

Applications

- Output rectifiers in switch mode power supplies (SMPS) and DC to DC converters
- Free-wheeling diode or boost diode in converters and motor control circuits
- Anti-parallel diode for high frequency switching devices such as IGBT
- Uninterruptible Power Supplies (UPS)
- Inductive heating and melting
- Ultrasonic cleaners and welders

Maximum Ratings

Characteristics	Symbol	Conditions	Max.	Unit
Peak Inverse Voltage	V _{RWM}	-	400	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _c =100 °C, rectangular wave form	10 (Per Leg)	A
			20(Total Device)	
Peak One Cycle Non- Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half sine pulse	125	А

Electrical Characteristics

Characteristics	Symbol	Conditions	Max.	Unit
Forward Voltage Drop ¹	V _{E1}	@10A, Pulse, T ₁ = 25 °C	1.3	V
	V _{F2}	@10A, Pulse, T = 125 °C	1.2	V
Reverse Current ¹	I _{B1}	$@V_{R} = Rated V_{R}, T_{J} = 25 \text{ °C}$	10	μA
	I _{R2}	$@V_{R} = Rated V_{R}, T_{J} = 125 \text{ °C}$	500	μA
Reverse Recovery Time	t _{rr1}	$I_{\rm F}$ =500mA, $I_{\rm R}$ =1A,and $I_{\rm rm}$ =250mA	45	ns

Footnote ¹: Pulse Width < 300 μ s, Duty Cycle <2%

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Thermal-Mechanical Specifications

Characteristics	Symbol	Conditions	Specification	Unit
Junction Temperature	T,	-	-55 to +150	°C
Storage Temperature	T _{stq}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _{ejc}	DC operation	5.0	°C/W
Approximate Weight	wt	-	2.0	g
Case Style	-	ITO-220AB	-	-

Figure 1: Typical Forward Characteristics



Figure 3: Typical Junction Capacitance



Figure 2: Typical Reverse Characteristics



Part Numbering and Marking System



*xxxxx is YYWWL

40

CT LF

YΥ

L

WW

- DUR = Device Type F = Package type
- F = Package type 20 = Forward Curre
 - = Forward Current (20A)
 - = Reverse Voltage (400V) = Configuration
 - = Littelfuse
 - = Year
 - = Week
 - = Lot Number



Packing Options				
Part Number	Marking	Packing Mode	M.O.Q	
DURF2040CT	DURF2040CT	50pcs / Tube	1000	

-

Dimensions-Package ITO-220AB







Symbol		Millimeters	
Symbol	Min	Тур	Max
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
С	0.55	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16	10.36
е		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
øP1	3.30	3.50	3.70
øP2	2.99	3.19	3.39
Q	2.50	2.70	2.90
θ1		5°	
θ2		4°	
θ3		10°	
θ4		5°	
θ5		5°	

Tube Specification ITO-220AB

